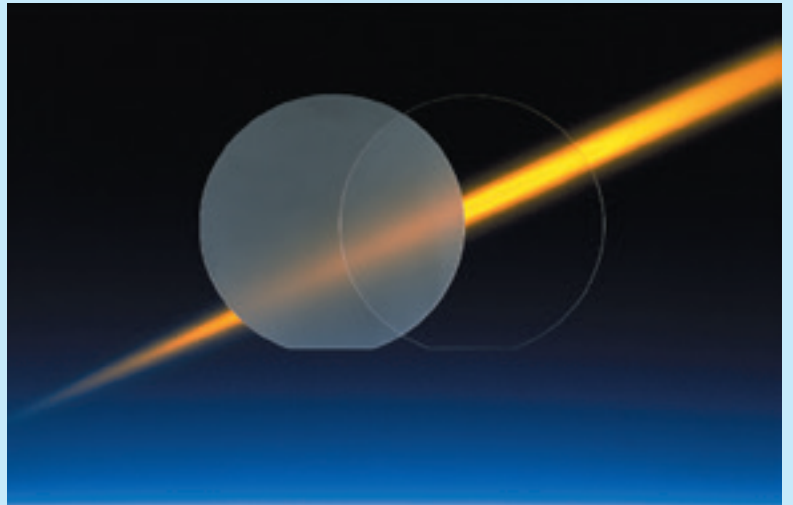


THE NEW VALUE FRONTIER



SINGLE CRYSTAL SAPPHIRE



SINGLE CRYSTAL SAPPHIRE

Single Crystal Sapphire is playing an ever-increasingly important role as a material for, high reliability Electronics today due to its excellent mechanical characteristics, chemical stability and light transmission.

Kyocera mass-produces Single Crystal Sapphire in a vertically integrated manner. From "pulling up" the raw material with EFG (Edge-Defined Film-Fed Growth) methods to machining, Kyocera produces and supplies various products with large diameters or specific shape requirements.

FEATURES OF EFG METHOD

- **Large Size Material**

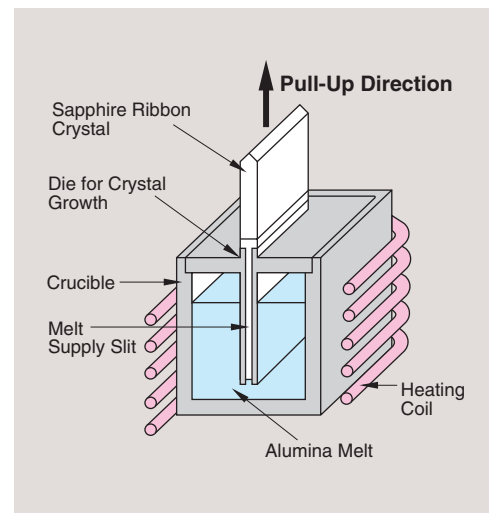
Sizing-up of materials allows for a broader range of applications and uses.

- **Production of Single Crystal Sapphire in Any Desired Sectional Shape**

Since any desired sectional shape can be obtained in the form of ribbons, tubes, rods, and others, cutting processes can be eliminated, allowing for a reduction in cost.

- **Control of Crystal Orientation**

Any axis and plane can be produced by instituting proper control during crystal growth.



EFG Method



CONTENTS

FEATURES OF EFG METHOD	P2
FEATURES OF SINGLE CRYSTAL SAPPHIRE.....	P3
SAPPHIRE MANUFACTURING PROCESS.....	P4
CHARACTERISTICS OF SINGLE CRYSTAL SAPPHIRE.....	P5
SAPPHIRE PRODUCTS.....	P6~P7

FEATURES OF SINGLE CRYSTAL SAPPHIRE

- **High Strength, High Rigidity, High Anti-Abrasion, High Anti-Heat, High Anti-Corrosion Characteristics, and High Anti-Plasma Characteristics.**

Because of these characteristics, Single Crystal Sapphire is widely used for precision mechanical parts.

- **Stable Dielectric Constant, Very Low Dielectric Loss, Good Electrical Insulation**

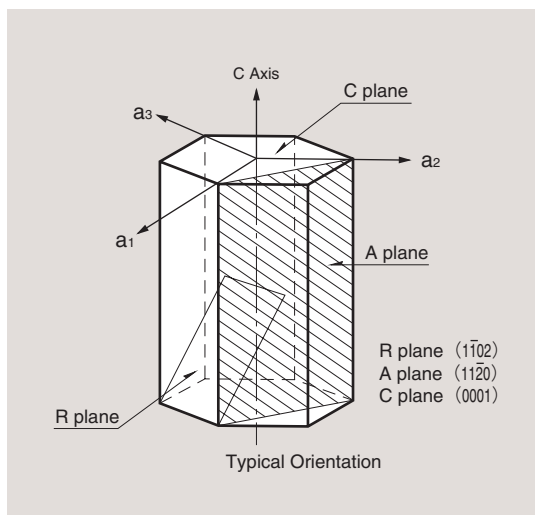
Single Crystal Sapphire is used as a material for substrates in super-high frequency regions. It is also used as an insulation material and microwave window. Single Crystal Sapphire has become indispensable in the Electronics Industries.

- **Excellent Light Transmission**

Single Crystal Sapphire is used for various kinds of vacuum equipment, windows in reaction furnace, scanner windows and caps for optical communication due to its excellent mechanical characteristics and heat resistance.

- **Good Thermal Conductivity and High Heat Resistance**

Excellent thermal conductivity at low temperatures allows Single Crystal Sapphire as a transparent material to be used in many diverse fields requiring thermal conduction and heat radiation.



Unit Cell of Sapphire

SAPPHIRE MANUFACTURING PROCESS

Sapphire Manufacturing Process

Growth of Raw Material



Grinding

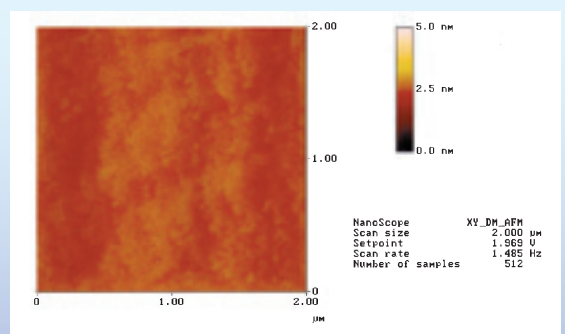


Lapping



Polishing

(Ra: $\leq 1 \text{ \AA}$)



Shape and Specifications

(unit: mm)

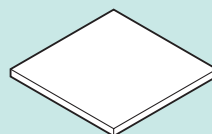
Substrate

Dimensions

Width 200max.
Length 300max.
Thickness 0.1~20

Crystal Orientation

R plane $\pm 2^\circ$
A plane $\pm 2^\circ$
C plane $\pm 2^\circ$



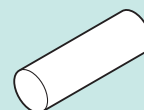
Rod

Dimensions

Diameter 0.5~20
Length 1,000max.

Crystal Orientation

C Axis in
Longitudinal
Direction



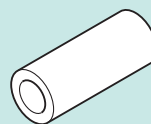
Tube

Dimensions

Inner Diameter 1.3~50
Tube Thickness 0.25~5
Length: 1,000mm max.

Crystal Orientation

C Axis in
Longitudinal
Direction



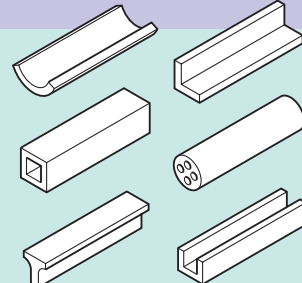
Others

Dimensions

To be
Customized

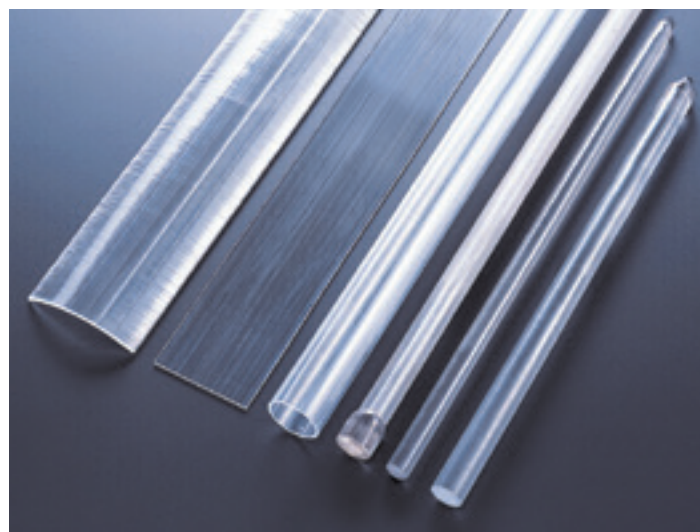
Crystal Orientation

To be
Customized



※Shapes other than above are available.

As-Grown Materials



CHARACTERISTICS OF SINGLE CRYSTAL SAPPHIRE

Characteristics of Kyocera's Single Crystal Sapphire

Mechanical Characteristics	Crystallographic Structure	Hexagonal System $a=4.763\text{\AA}$ $c=13.003\text{\AA}$ Rhombohedral Single crystal
	Reference Density	$3.97 \times 10^3 \text{ kg/m}^3$
	Vickers Hardness	22.5GPa (HV1 (Load=9.807N))
	Flexural Strength	690MPa
	Tensile Strength	2250MPa (Diameter 0.25mm Filament 25°C)
	Compressive Strength	2,940MPa
	Young's Modulus	470GPa
	Poisson's Ratio	0.18~0.29
Thermal Characteristics	Melting Point	2,053°C
	Coefficient of Linear Thermal Expansion	40~400°C C parallel to C axis $7.7 \times 10^{-6}/\text{°C}$ 40~400°C C perpendicular to C axis $7.0 \times 10^{-6}/\text{°C}$
	Thermal Conductivity	20°C 42W/(m·K)
	Specific Heat	$0.75 \times 10^3 \text{ J/(kg·K)}$
	Emittance	<0.02 ($\lambda=2.6\sim 3.7\mu\text{m}$ 880°C)
Electrical Characteristics	Dielectric strength	$48 \times 10^6 \text{ V/m}$
	Volume Resistance	20°C $> 10^{14} \Omega \cdot \text{cm}$ 500°C $10^{11} \Omega \cdot \text{cm}$
	Dielectric Constant	C parallel to C axis 11.5 (1MHz) C perpendicular to C axis 9.3 (1MHz)
	Dielectric Loss Angle	$< 1 (\times 10^{-4})$ (1MHz)
	Loss Factor	$— (\times 10^{-4})$
	Dielectric Loss Tangent	10^{-4} max.
Optical Characteristics	Index of Refraction	No=1.768 Ne=1.760 @589nm
	Optical Transmission	Refer to Fig.5

※ These figures are representative.

※ Each Crystal Orientation has different characteristics.

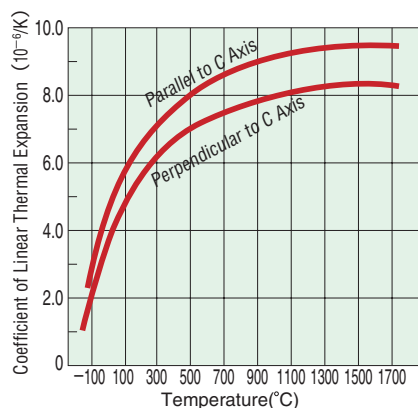


Fig. 1 Thermal Expansion vs. Temperature

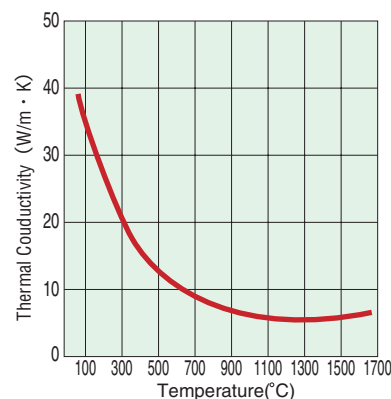


Fig. 2 Thermal Conductivity vs. Temperature

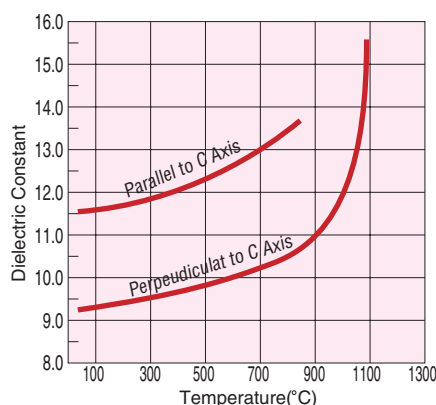


Fig. 3 Dielectric Constant vs. Temperature

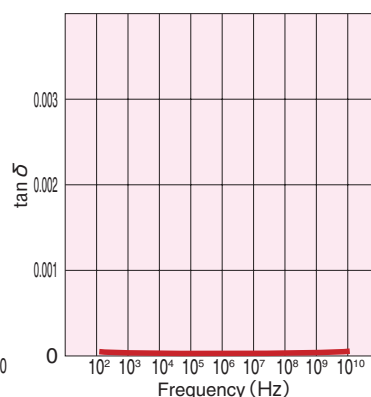


Fig. 4 Dielectric Loss vs. Frequency

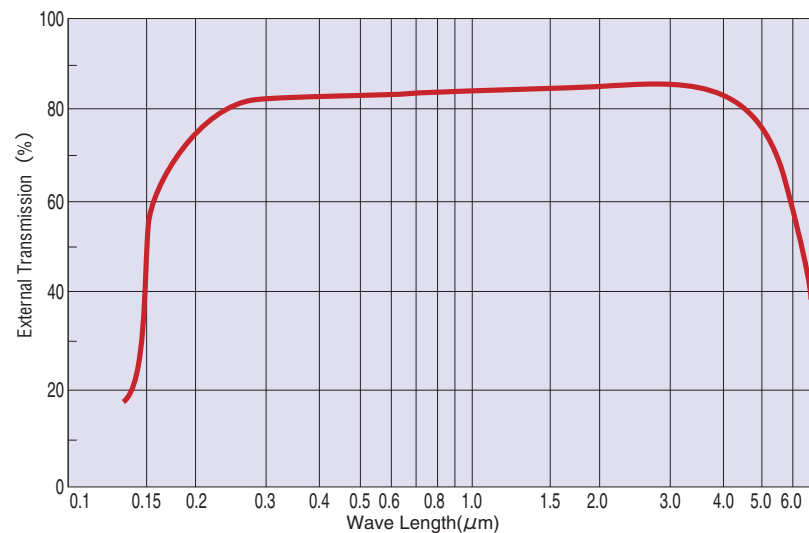


Fig. 5 Transmission vs. Wave Length

NOTE: • Transmittance range varies depending on thickness of Sapphire Products.

• Interfacial Reflection included

• Thickness 1mm.

(Unit:mm)

Standard Dimensional Tolerance

Nominal Dimension : a	$1 > a$	$1 \leq a \leq 4$	$4 < a \leq 25$	$25 < a \leq 102$	$102 < a \leq 190$	$190 < a$
Tolerance (±)	0.05	0.1	0.2	0.25	0.5	1

● Machining accuracy: Tube 1.A.10.A. and standard tube thickness tolerance... ± 0.25 .

Hole diameter and standard pitch tolerance... ± 0.1

SAPPHIRE PRODUCTS

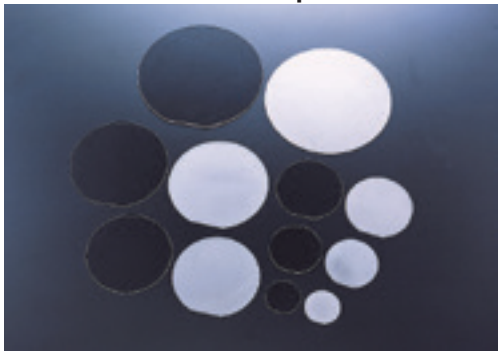
Substrate



Application

- (1) High Brightness LED
 - (2) HB-LED Semiconductor, Piezoelectric Semiconductor, Superconductor, Thin Film Substrate.
 - (3) MR Sensor, Precision Resistor
 - (4) Optical Devices
 - (5) Thin Film HIC
- Single Crystal Sapphire is widely used substrate material for blue, green, ultraviolet and white LEDs. It has excellent features as a base substrate for GaN deposition and great mass-productivity. In addition, it can meet future larger-size demand.
 - Single Crystal Sapphire is used as a base substrate in thin film deposition because of its lattice alignment match with a variety of semiconductor materials combined with excellent thermal and chemical stability.

2"-8" substrate for Optical Devices



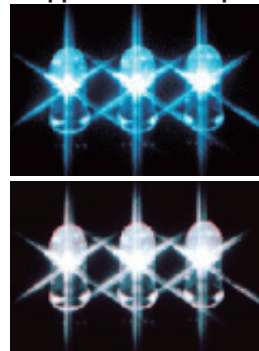
Standard Dimension and Tolerance

	Size	O.F. Length
8"	$\phi 200 \pm 0.25 \times 0.725 \pm 0.05$	55~60
6"	$\phi 150 \pm 0.25 \times 0.625 \pm 0.05$	45~50
5"	$\phi 125 \pm 0.25 \times 0.625 \pm 0.05$	40~45
4"	$\phi 100 \pm 0.25 \times 0.53 \pm 0.05$	30~35
3"	$\phi 76.2 \pm 0.25 \times 0.43 \pm 0.05$	19~25
2"	$\phi 50.8 \pm 0.25 \times 0.33 \pm 0.05$	13~19

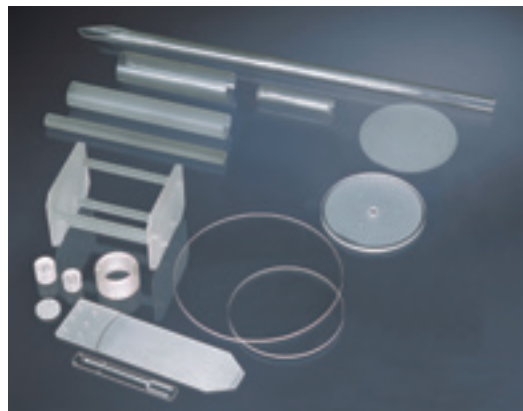
※ Specifications other than above are available.

※ Available sizes are dependent on a crystal orientation.
 Sizes and tolerances other than the above table are also available under customer requirements. Please contact or send your requirements to Kyocera.

Application Examples



Semiconductor Process Equipment Parts



Application

- (1) Carrier Plate
- (2) Microwave Entrance Tube
- (3) Dummy Water
- (4) Handling Arm
- (5) Vacuum Chuck
- (6) Window

- It is used as various Semiconductor Process Equipment due to its high anti-plasma and high anti-heat characteristics.



(1)



(2)



(3)



(4)

Optical Products for LCD Projectors



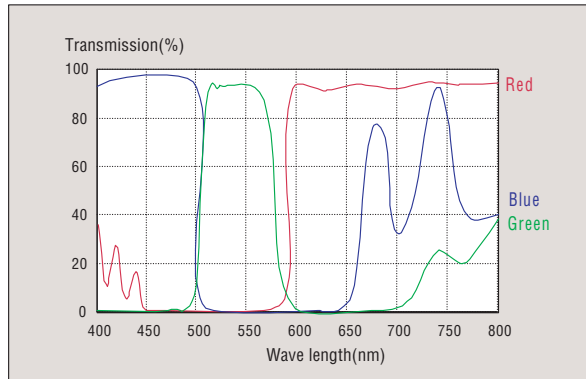
JP Patent No. 3091183, No.3443549
U.S. Patent No. 6577375, No.6642989

Application

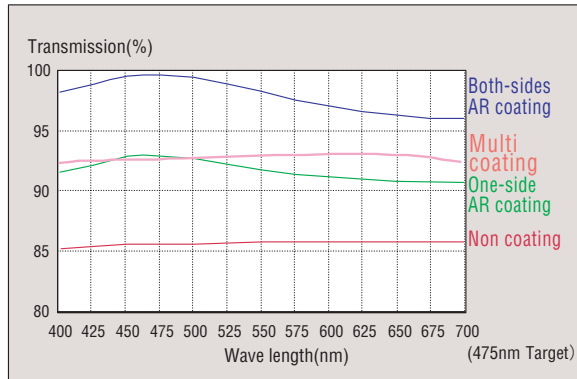
- (1) Sapphire Plate
 - Polarizing Film Attached
 - Holder Assembled
 - Dichroic Filter
- (2) LCD Projector
 - Dust Control Plate

- Sapphire material realizes high brightness and high picture quality for LCD projectors due to its high thermal conductivity and optical properties.
- Coating such as Dichroic Filter, to prevent reflection features is available.
- Standard sizes to fit in various LCD panels are available.

Selected Transmission Layer for Wave Length Optical Transmission



AR Coat External Transmission



※Characteristic values are subjected to change due to each specs or conditions.

Optical Products



Application

- (1) POS Scanner Window (SOG)
- (2) Window
- (3) Cap for Optical Communication
- (4) Infrared Measuring Device Window
- (5) Coin Sensor
- (6) Lamp External Tube
 - High Pressure Sodium, Xenon, Ultra Pressure mercury
 - Metallic Halide
- (7) Light Receiving Window Accelerating Tube

Others



Application

- (1) Fiber Bar Guide
- (2) Insulating Plate and Rod
- (3) Single Crystal Material Sheel Holder
- (4) Biomaterial (BIOCERAM®)
- (5) Watch Window
- (6) NMR Protection Tube
- (7) Thermocouple Protection Tube
- (8) HDC Resonator Rod

<JAPAN: Headquarters>

KYOCERA Corporation

Corporate Fine Ceramics Group

6 Takeda Tobadono-cho, Fushimi-ku, Kyoto 612-8501, Japan
Tel: +81-(0)75-604-3441 Fax: +81-(0)75-604-3438



WEB

global.kyocera.com/prdct/fc/index.html



E-mail
inquiries

webmaster.fc@kyocera.jp

<U.S.A.>

KYOCERA International, Inc.

San Jose, CA

49070 Milmont Dr. Fremont, CA 94538
Tel: +1-510-257-0200 Fax: +1-510-257-0125

San Diego, CA

8611 Balboa Avenue, San Diego, CA 92123
Tel: +1-858-614-2520 Fax: +1-858-715-0871

Chicago, IL

25 NW Point Blvd., #660 Elk Grove Village, IL 60007
Tel: +1-847-981-9494 Fax: +1-847-981-9495

Boston, MA

24 Superior Dr, Suite 106, Natick, MA 01760
Tel: +1-508-651-8161 Fax: +1-508-655-9139

Mountain Home, NC

100 Industrial Park Rd, Hendersonville, NC 28792
Tel: +1-828-693-8244 Fax: +1-828-692-1340

New Jersey, NJ

220 Davidson Ave., Suite 108, Somerset, NJ 08873
Tel: +1-732-563-4336 Fax: +1-732-627-9594

Austin, TX

7801 Capital of Texas Highway, Ste 330 Austin, TX 78731
Tel: +1-512-336-1725 Fax: +1-512-336-8189

Vancouver, WA

5713 East Fourth Plain Blvd., Vancouver, WA 98661
Tel: +1-360-696-8950 Fax: +1-360-696-9804

<EUROPE>

KYOCERA Europe GmbH

Esslingen, Germany

Fritz-Mueller-Strasse 27, 73730 Esslingen, Germany
Tel: +49-(0)711-93934-0 Fax: +49-(0)711-93934-950

Neuss, Germany

Hammfelddamm 6 41460 Neuss, Germany
Tel: +49-(0)2131-1637-0 Fax: +49-(0)2131-1637-150

KYOCERA Fineceramics Ltd.

U.K.

Prospect House, Archipelago, Lyon Way, Frimley, Surrey
GU16 7ER, U.K.
Tel: +44-(0)1276-6934-50 Fax: +44-(0)1276-6934-60

KYOCERA Fineceramics S.A.S.

France

Parc Tertiaire, Silic, 21 Rue De Villeneuve
BP 90439 94583 Rungis Cedex, France
Tel: +33-(0)141-7373-30 Fax: +33-(0)141-7373-59

<ASIA>

KYOCERA Korea Co., Ltd.

Korea

13F KAMCO Tangjae Tower, 262 Kangnamdae-ro
Kangnam-gu, Seoul, 06265
Tel: +82-(0)2-3463-3538 Fax: +82-(0)2-3463-3539

KYOCERA (China) Sales & Trading Corporation

Shanghai

Floor 9, Dushi Headquarters Building, No. 168, Middle Xizang Road, Shanghai,
200001

Tel: +86-(0)21-5877-5366 Fax: +86-(0)21-5888-5096

Shenzhen

Unit 06-08, 29/F, AVIC Center NO.1018 Huafu Road,
Futian District, Shenzhen, Guangdong, 518033
Tel: +86-(0)755-8272-4107 Fax: +86-(0)755-8279-0487

KYOCERA (Hong Kong) Sales & Trading Ltd.

Hong Kong

Room 801-802, Tower 1, South Seas Centre,
75 Mody Road, Tsimshatsui East, Kowloon, Hong Kong
Tel: +852-(0)2722-3912 Fax: +852-(0)2724-4501

KYOCERA Asia Pacific, Ltd.

Taiwan

8FL., No.101, Sec.2, Nanjing East Road, Taipei 10457, Taiwan
Tel: +886-(0)2-2567-2008 Fax: +886-(0)2-2567-2700

Singapore

298 Tiong Bahru Road, #13-03/05 Central Plaza, 168730, Singapore
Tel: +65-6271-0500 Fax: +65-6271-0600

Philippines

11B, Kingston Tower, Block 2, Lot 1, Acacia Avenue,
Madrigal Business Park, Alabang, Muntinlupa City 1780, Philippines
Tel: +63-(0)2-771-0618 Fax: +63-(0)2-775-0532

KYOCERA Asia Pacific (Thailand) Co., Ltd.

Thailand

1 Capital Work Place, Building 7th Floor, Soi Chamchan, Sukhumvit 55
Road, Klongton Nua, Wattana, Bangkok 10110, Thailand.
Tel: +66-(0)2030-6688 Fax: +66-(0)2030-6600

KYOCERA Sdn. Bhd.

Malaysia

Lot 4A, Lower Level 3, Hotel Equatorial, Penang No.1,
Jalan Bukit Jambul 11900 Penang, Malaysia
Tel: +60-4-641-4190 Fax: +60-4-641-4209

KYOCERA Asia Pacific India Pvt. Ltd.

India

1004A & 1004B, 10th Floor, JMD Regent Square, M.G. Road Gurugram Haryana,
India
Tel: +91-124-4714298 Fax: +91-124-4683378